## NSN 5962-01-113-9160

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-113-9160 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and programmable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 0.3 volts power source **Time Rating Per Chacteristic:** 500.00 nanoseconds propagation delay time, low to high level output and 500.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:** 

Fiig:

**Demilitarization:** Yes - demil/mli

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